# NSN 5962-01-114-3322

Memory Microcircuit - Page 1 of 1



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# **Body Length:**

Between 0.750 inches and 0.785 inches

# **Body Width:**

Between 0.220 inches and 0.310 inches

# **Body Height:**

Between 0.145 inches and 0.185 inches

## **Operating Tempurature Range:**

-55.0/+125.0 degrees celsius

#### Storage Tempurature Range:

-65.0/+150.0 degrees celsius

#### **End Application:**

F16maintntrng fscm 81755

#### **Features Provided:**

Hermetically sealed and monolithic and bipolar and burn in, mil-std-883, class b and programmable and w/decoded output and w/enable

#### **Inclosure Material:**

# Ceramic and glass

## Inclosure Configuration:

Dual-in-line

#### **Output Logic Form:**

Transistor-transistor logic

## Input Circuit Pattern:

10 input

### **Terminal Surface Treatment:**

Solder

## Voltage Rating And Type Per Characteristic:

5.5 volts power source

## **Time Rating Per Chacteristic:**

60.00 nanoseconds propagation delay time, low to high level output and 60.00 nanoseconds propagation delay time, high to low level output

#### Memory Device Type:

Rom

#### Test Data Document:

09344-34811 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.; excludes any specification, standard or other document that may be referenced in a basic governing drawing)

## Terminal Type And Quantity:

16 printed circuit

Shelf Life:

N/a

# Unit Of Measure:

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# Demilitarization:

Yes - demil/mli

Fiig:

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